TOSHIBA Field Effect Transistor with Built-in Schottky Barrier Diode

Silicon N-Channel MOS Type (U-MOS V-H)

TPC8A06-H

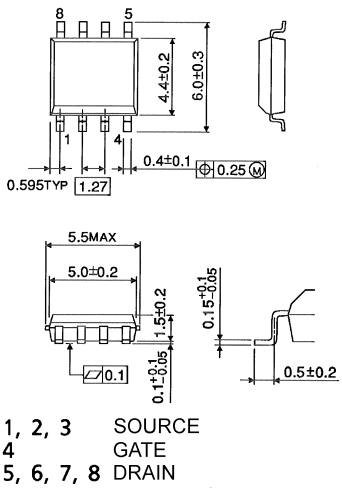
High Efficiency DC-DC Converter Applications

Notebook PC Applications

Portable Equipment Applications

- Built-in schottky barrier diode
  Low forward voltage: V_{DSF} = 0.6 V (max)
- High-speed switching
- Small gate charge: Q_{SW} = 4.5 nC (typ.)
- Low drain-source ON-resistance:
  $R_{DS\ (ON)}$ = 9.2 mΩ (typ.)(V_{GS} = 4.5 V)
- High forward transfer admittance: $|Y_{fs}|$ = 37 S (typ.)
- Low leakage current: I_{DSS} = 100 μA (max) (V_{DS} = 30 V)
- Enhancement mode: V_{th} = 1.3 to 2.3 V (V_{DS} = 10 V, I_D = 1 mA)

Unit: mm



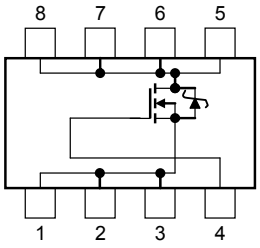
JEDEC	—
JEITA	—
TOSHIBA	2-6J1B

Weight: 0.085g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	30	V
Drain-gate voltage (R_{GS} = 20 kΩ)		V_{DGR}	30	V
Gate-source voltage		V_{GSS}	±20	V
Drain current	DC (Note 1)	I_D	12	A
	Pulsed (Note 1)	I_{DP}	48	
Drain power dissipation (t = 10 s) (Note 2a)		P_D	1.9	W
Drain power dissipation (t = 10 s) (Note 2b)		P_D	1.0	W
Single-pulse avalanche energy (Note 3)		E_{AS}	94	mJ
Avalanche current		I_{AR}	12	A
Repetitive avalanche energy (Tc=25°C) (Note 4)		E_{AR}	0.10	mJ
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	−55 to 150	°C

Circuit Configuration



Note: For Notes 1 to 4, refer to the next page.

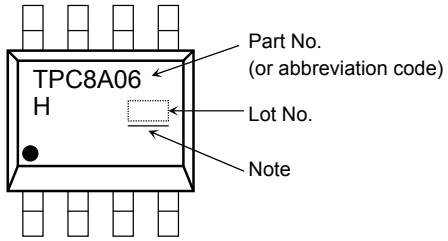
Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.

Thermal Characteristics

Characteristic	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	$R_{th\ (ch\text{-}a)}$	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	$R_{th\ (ch\text{-}a)}$	125	°C/W

Marking (Note 5)

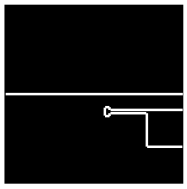


Note : A line under a Lot No. identifies the indication of product Labels
[[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment

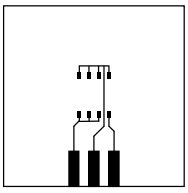
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a) Device mounted on a glass-epoxy board (a) (b) Device mounted on a glass-epoxy board (b)



FR-4
25.4 × 25.4 × 0.8
(Unit: mm)

(a)



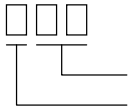
FR-4
25.4 × 25.4 × 0.8
(Unit: mm)

(b)

Note 3: V_{DD} = 24 V, T_{ch} = 25°C (initial), L = 500 μH, R_G = 25 Ω, I_{AR} = 12 A

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

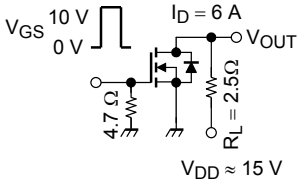
Note 5: * Weekly code: (Three digits)



Week of manufacture
(01 for the first week of the year, continuing up to 52 or 53)

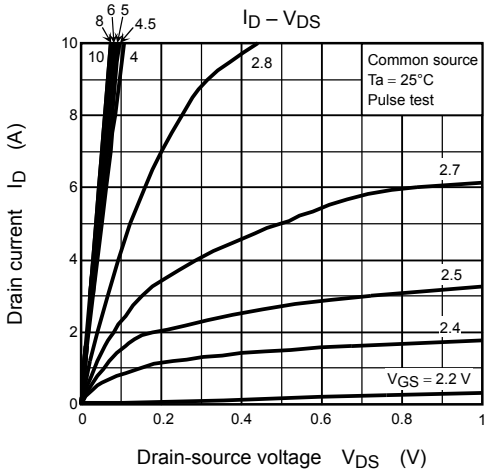
Year of manufacture
(The last digit of the year)

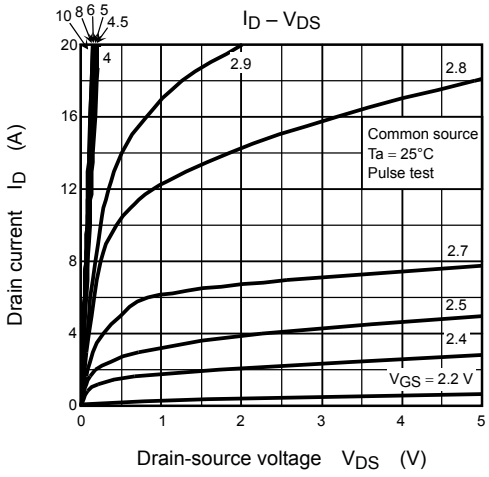
Electrical Characteristics (Ta = 25°C)

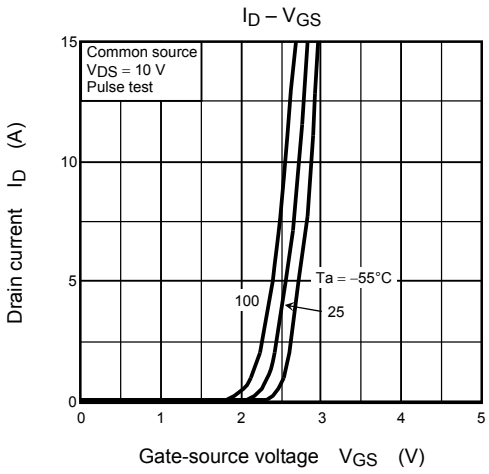
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	V_{GS} = ±20 V, V_{DS} = 0 V	—	—	±100	nA
Drain cutoff current		I_{DSS}	V_{DS} = 30 V, V_{GS} = 0 V	—	—	100	μA
Drain-source breakdown voltage		$V_{(BR)\ DSS}$	I_D = 10 mA, V_{GS} = 0 V	30	—	—	V
		$V_{(BR)\ DSX}$	I_D = 10 mA, V_{GS} = −20 V	15	—	—	
Gate threshold voltage		V_{th}	V_{DS} = 10 V, I_D = 1 mA	1.3	—	2.3	V
Drain-source ON-resistance		$R_{DS\ (ON)}$	V_{GS} = 4.5 V, I_D = 6 A	—	9.2	12.9	mΩ
			V_{GS} = 10 V, I_D = 6 A	—	7.2	10.1	
Forward transfer admittance		$\|Y_{fs}\|$	V_{DS} = 10 V, I_D = 6 A	19	37	—	S
Input capacitance		C_{iss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz	—	1400	1800	pF
Reverse transfer capacitance		C_{rss}		—	54	80	
Output capacitance		C_{oss}		—	380	—	
Gate resistance		rg	V_{DS} = 10 V, V_{GS} = 0 V, f = 5 MHz	—	1.6	2.4	Ω
Switching time	Rise time	t_r	 Duty ≤ 1%, t_w = 10 μs	—	2.4	—	ns
	Turn-on time	t_{on}		—	8.6	—	
	Fall time	t_f		—	3.5	—	
	Turn-off time	t_{off}		—	22	—	
Total gate charge (gate-source plus gate-drain)		Q_g	V_{DD} ≈ 24 V, V_{GS} = 10 V, I_D = 12 A	—	19	—	nC
			V_{DD} ≈ 24 V, V_{GS} = 5 V, I_D = 12 A	—	9.6	—	
Gate-source charge 1		Q_{gs1}	V_{DD} ≈ 24 V, V_{GS} = 10 V, I_D = 12 A	—	4.6	—	
Gate-drain (“Miller”) charge		Q_{gd}		—	2.5	—	
Gate switch charge		Q_{SW}		—	4.5	—	

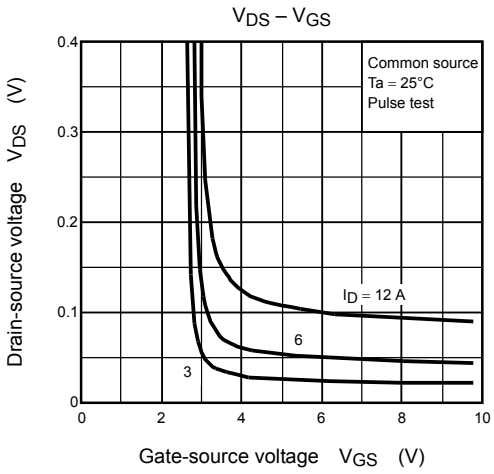
Source-Drain Ratings and Characteristics (Ta = 25°C)

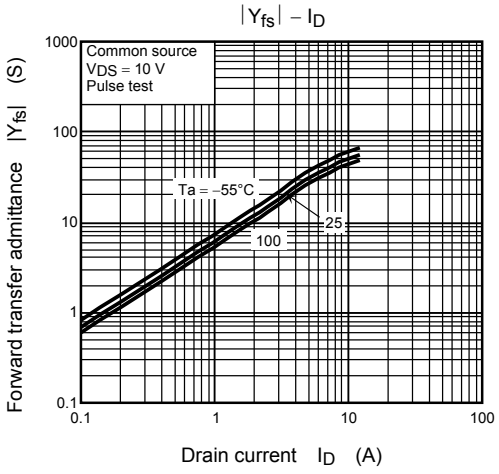
Characteristic		Symbol	Test Condition	Min	Typ.	Max	Unit
Peak forward current	Pulse (Note 1)	I_{FP}	—	—	—	48	A
Forward voltage (diode)		V_{DSF}	I_{DR} = 1 A, V_{GS} = 0 V	—	−0.4	−0.6	V
			I_{DR} = 12 A, V_{GS} = 0 V	—	—	−1.2	V

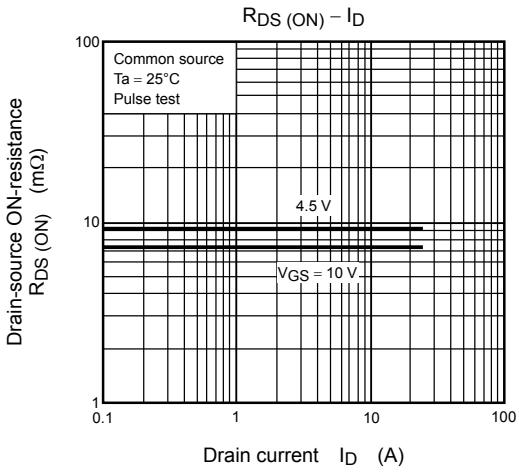




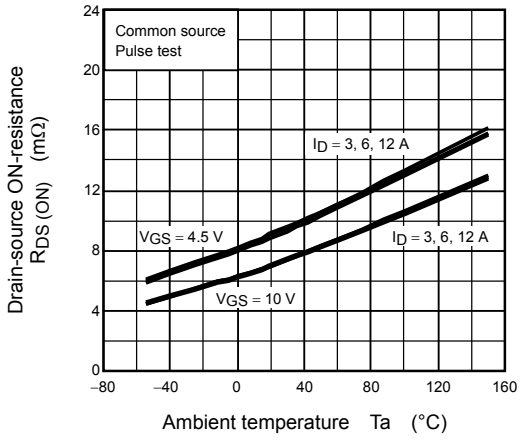




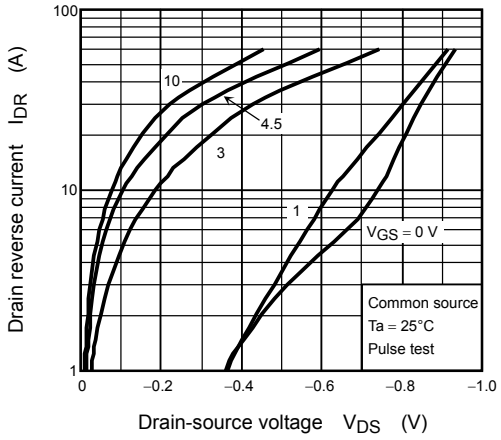




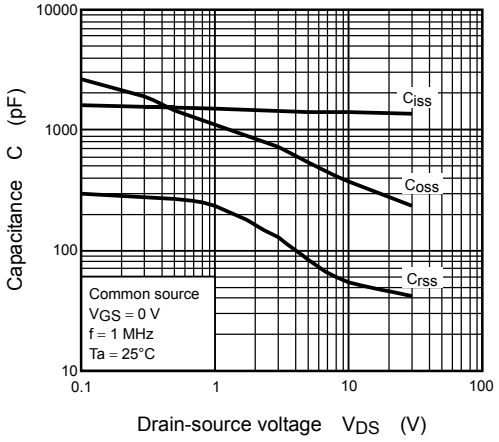
$R_{DS\ (ON)}$ – Ta



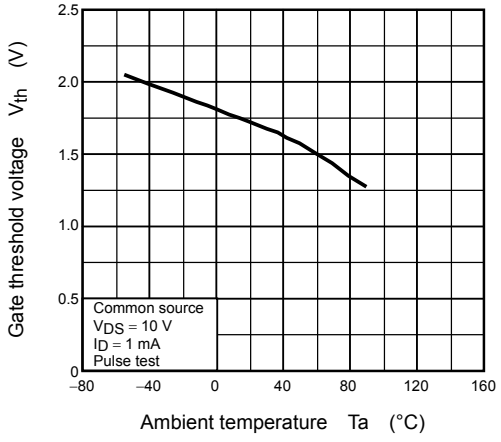
I_{DR} – V_{DS}



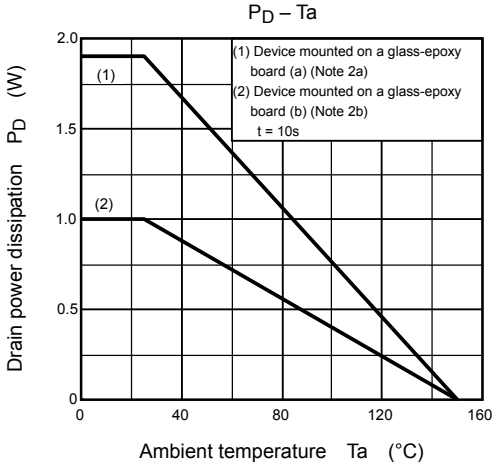
Capacitance – V_{DS}



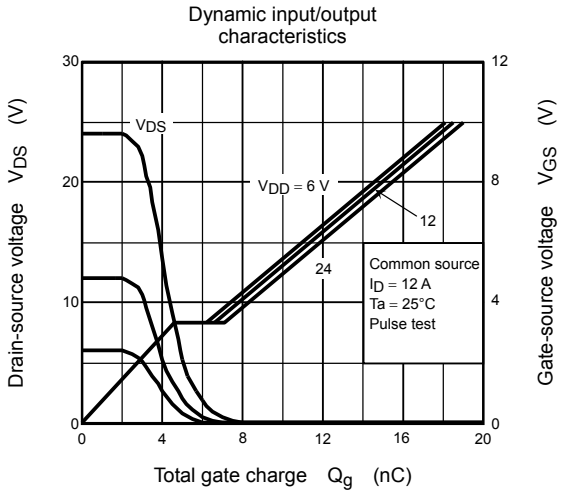
V_{th} – Ta

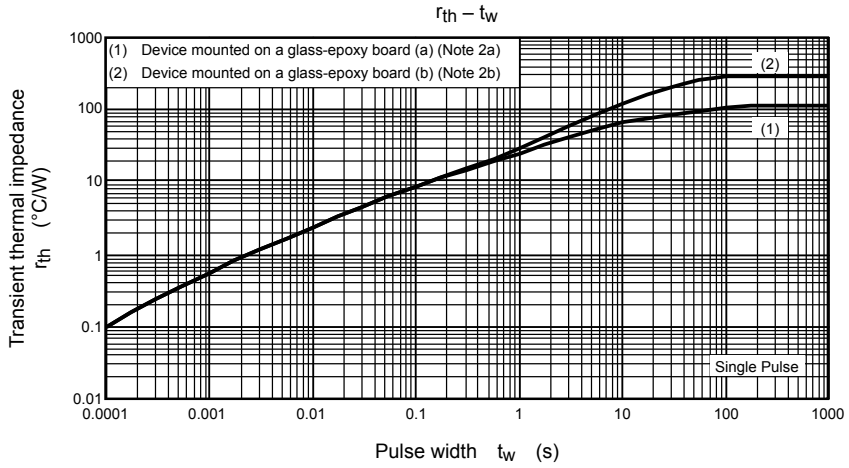


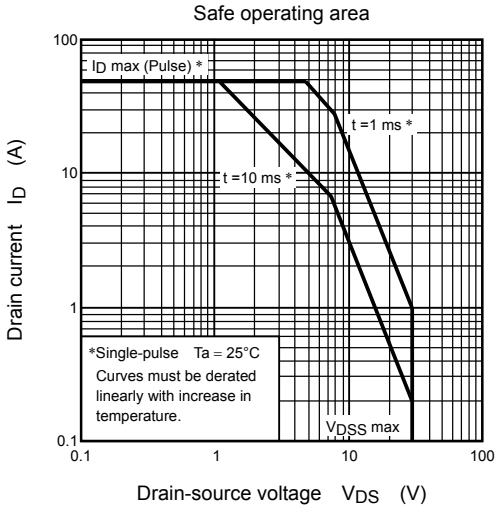
P_D – Ta



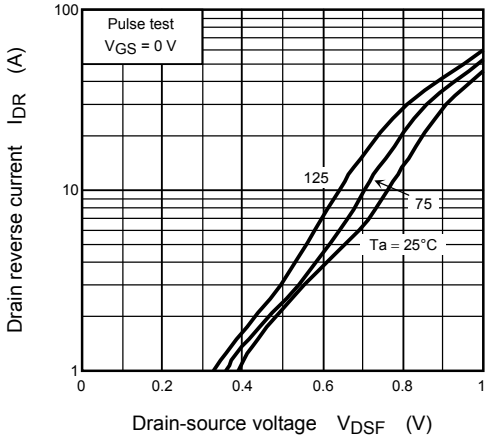
Dynamic input/output characteristics



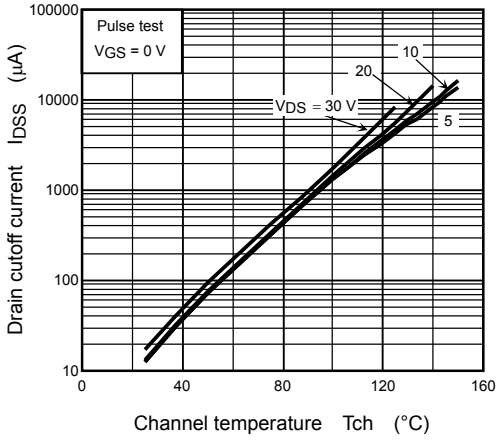




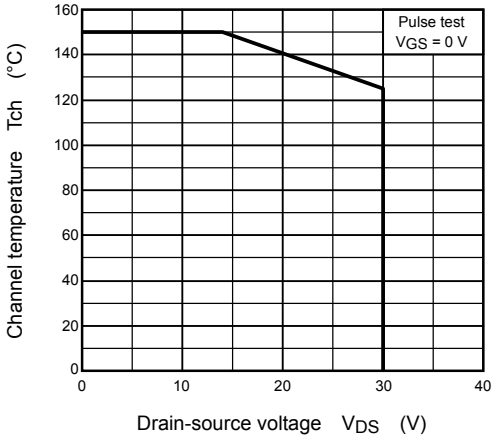
I_{DR} – V_{DSF}



I_{DSS} – Tch (typ.)



Tch – V_{DS}



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